

## PEMD14

# 50 V, 100 mA NPN/PNP resistor-equipped transistor; R1 = 47 k $\Omega$ , R2 = open

27 April 2023

Product data sheet

## 1. General description

NPN/PNP Resistor-Equipped Transistor (RET) in a SOT666 ultra small and flat lead Surface-Mounted Device (SMD) plastic package.

PNP/PNP complement: PEMB14 NPN/NPN complement: PEMH14

### 2. Features and benefits

- Built-in bias resistors
- · Simplifies circuit design
- Reduces component count
- Reduces pick and place cost

## 3. Applications

- Low current peripheral driver
- · Control of IC inputs
- · Replacement of general-purpose transistors in digital applications

## 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor							
V <sub>CEO</sub>	collector-emitter voltage	open base	[1]	-	-	50	V
Io	output current		[1]	-	-	100	mA
R1	bias resistor 1 (input)		[2]	33	47	61	kΩ

- [1] For the PNP transistor with negative polarity.
- [2] See section "Test information" for resistor calculation and test conditions.



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## 5. Pinning information

**Table 2. Pinning information** 

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1		O1 I2 GND2
2	I1	input (base) TR1	6 5 4	
3	O2	output (collector) TR2		R1 R
4	GND2	GND (emitter) TR2		TR1
5	12	input (base) TR2		R1 R1
6	O1	output (collector) TR1	1 2 3 <b>SOT666</b>	GND1 I1 O2 006aaa269

## 6. Ordering information

**Table 3. Ordering information** 

Type number	Package		
	Name	Description	Version
PEMD14	SOT666	plastic, surface-mounted package; 6 leads; 0.5 mm pitch; 1.6 mm x 1.2 mm x 0.55 mm body	<u>SOT666</u>

## 7. Marking

#### Table 4. Marking codes

Type number	Marking code
PEMD14	5B

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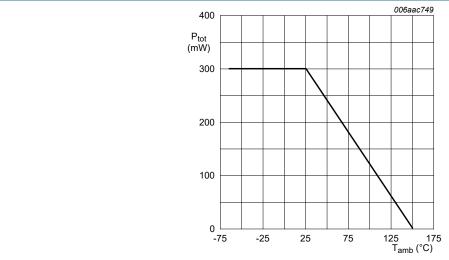
## 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transist	or		'			
V <sub>CBO</sub>	collector-base voltage	open emitter	[1]	-	50	V
$V_{CEO}$	collector-emitter voltage	open base	[1]	-	50	V
V <sub>EBO</sub>	emitter-base voltage	open collector	[1]	-	5	V
VI	input voltage	TR1 (NPN)		-5	40	V
		TR2 (PNP)		-40	5	V
Io	output current		[1]	-	100	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[2] [3]	-	200	mW
Per device	·		·	'		'
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[2] [3]	-	300	mW
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-65	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

- [1] For the PNP transistor with negative polarity.
- [2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.
- [3] Reflow soldering is the only recommended soldering method.



FR4 PCB, single-sided, 35 µm copper, tin-plated and standard footprint

Fig. 1. Per device: Power derating curve

50 V, 100 mA NPN/PNP resistor-equipped transistor; R1 = 47 k $\Omega$ , R2 = open

## 9. Thermal characteristics

**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1] [2]	-	-	625	K/W
Per device	Per device						
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1] [2]	-	-	416	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Reflow soldering is the only recommended soldering method.

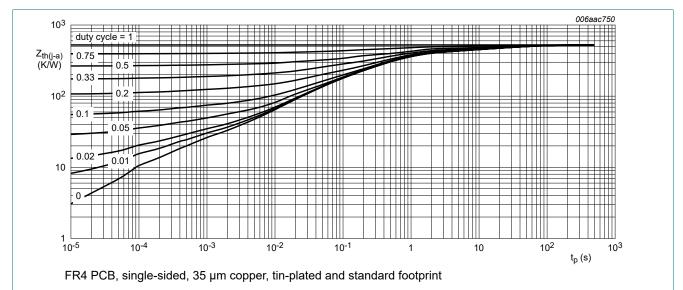


Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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## 10. Characteristics

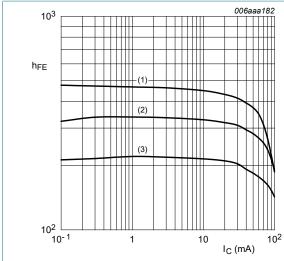
#### **Table 7. Characteristics**

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transist	tor						
V <sub>(BR)CBO</sub>	collector-base breakdown voltage	$I_C = 100 \ \mu A; I_E = 0 \ A; T_{amb} = 25 \ ^{\circ}C$	[1]	50	-	-	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	$I_C = 2 \text{ mA}; I_B = 0 \text{ A}; T_{amb} = 25 ^{\circ}\text{C}$	[1]	50	-	-	V
I <sub>CBO</sub>	collector-base cut-off current	V <sub>CB</sub> = 50 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C	[1]	-	-	100	nA
I <sub>CEO</sub> collector-emitter cut-o	collector-emitter cut-off	V <sub>CE</sub> = 30 V; I <sub>B</sub> = 0 A; T <sub>amb</sub> = 25 °C	[1]	-	-	1	μA
	current	$V_{CE} = 30 \text{ V}; I_B = 0 \text{ A}; T_j = 150 \text{ °C}$	[1]	-	-	50	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = 5 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C	[1]	-	-	100	nA
h <sub>FE</sub>	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 1 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$	[1]	100	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$	[1]	-	-	150	mV
$V_{I(off)}$	off-state input voltage	$V_{CE} = 5 \text{ V}; I_{C} = 0.1 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$	[1]	-	0.6	0.5	V
V <sub>I(on)</sub>	on-state input voltage	V <sub>CE</sub> = 0.3 V; I <sub>C</sub> = 10 mA	[1]	4	2.5	-	V
R1	bias resistor 1 (input)		[2]	33	47	61	kΩ
Transistor 1	TR1 (NPN)						
C <sub>c</sub>	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = 0 \text{ A}; i_e = 0 \text{ A}; f = 1 \text{ MHz}; $ $T_{amb} = 25 \text{ °C}$		-	-	2.5	pF
f <sub>T</sub>	transition frequency	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 10 mA; f = 100 MHz; T <sub>amb</sub> = 25 °C	[3]	-	230	-	MHz
Transistor 1	TR2 (PNP)						
C <sub>c</sub>	collector capacitance	$V_{CB}$ = -10 V; $I_{E}$ = 0 A; $i_{e}$ = 0 A; $f$ = 1 MHz; $T_{amb}$ = 25 °C		-	-	3	pF
f <sub>T</sub>	transition frequency	$V_{CE}$ = -5 V; $I_{C}$ = -10 mA; f = 100 MHz; $T_{amb}$ = 25 °C	[3]	-	180	-	MHz

For the PNP transistor with negative polarity.
See section "Test information" for resistor calculation and test conditions.

<sup>[2]</sup> [3] Characteristics of built-in transistor

#### 50 V, 100 mA NPN/PNP resistor-equipped transistor; R1 = 47 k $\Omega$ , R2 = open

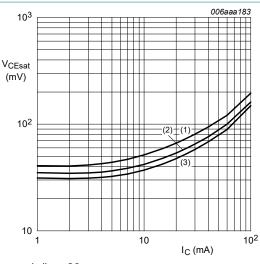


$$V_{CE} = 5 V$$

$$(1) I_{amb} = 100 °($$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

TR1 (NPN): DC current gain as a function of Fig. 3. collector current; typical values



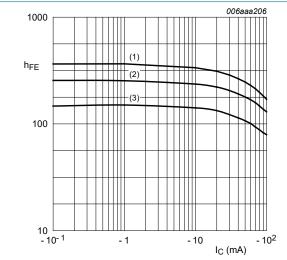
$$I_{\rm C}/I_{\rm B} = 20$$

$$I_{C}/I_{B} = 20$$
(1)  $T_{amb} = 100 \, ^{\circ}C$ 
(2)  $T_{amb} = 25 \, ^{\circ}C$ 
(3)  $T_{amb} = -40 \, ^{\circ}C$ 

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 4. TR1 (NPN): Collector-emitter saturation voltage as a function of collector current; typical values



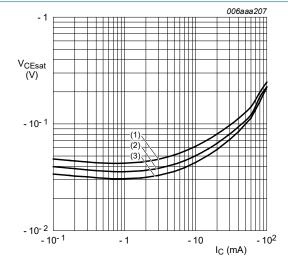
$$V_{CE}$$
 = -5  $V$ 

$$(1) T_{amb} = 100 °C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -40 \, ^{\circ}C$$

TR2 (PNP): DC current gain as a function of Fig. 5. collector current; typical values



$$I_{\rm C}/I_{\rm B} = 20$$

$$(1) T_{amb} = 100 °C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 6. TR2 (PNP): Collector-emitter saturation voltage as a function of collector current; typical values

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## 11. Test information

#### **Resistor calculation**

• Calculation of bias resistor 1 (R1)

$$R_I = \frac{V(I_2) - V(I_I)}{I_2 - I_I}$$

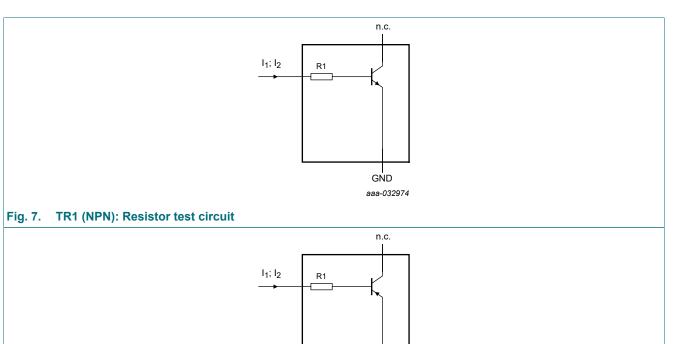


Fig. 8. TR2 (PNP): Resistor test circuit

#### **Resistor test conditions**

**Table 8. Resistor test conditions** 

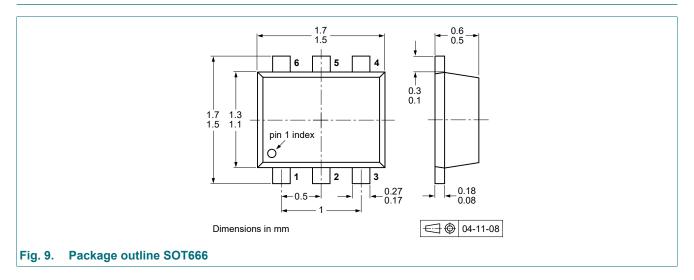
PEMD14	R1 (kΩ)	R2 (open)	Test conditions	
			I <sub>1</sub>	l <sub>2</sub>
TR1 (NPN)	47	-	60 μA	110 μΑ
TR2 (PNP)	47	-	-60 µA	-110 μA

aaa-032975

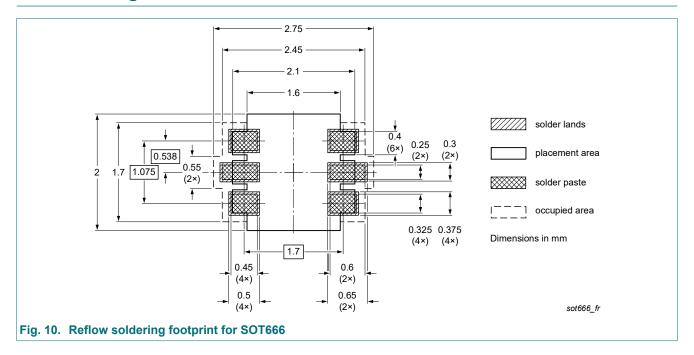
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50 V, 100 mA NPN/PNP resistor-equipped transistor; R1 = 47 k $\Omega$ , R2 = open

## 12. Package outline



## 13. Soldering



50 V, 100 mA NPN/PNP resistor-equipped transistor; R1 = 47 k $\Omega$ , R2 = open

## 14. Revision history

#### Table 9. Revision history

Tuble of Novicion motory						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PEMD14 v.3	20230427	Product data sheet	-	PEMD14_PUMD14_2		
Modifications:	Nexperia.  Legal texts have bee Family data sheet sp Section "Packing info	ta sheet has been redesion adapted to the new constituted to single type data permation" removed.	mpany name where approsheets.	. 0		
PEMD14_PUMD14_2	20090902	Product data sheet	-	PEMD14_PUMD14_1		
PEMD14_PUMD14_1	20050114	Product data sheet	-	-		

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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## **Contents**

1. General description	1
2. Features and benefits	1
3. Applications	1
4. Quick reference data	1
5. Pinning information	2
6. Ordering information	2
7. Marking	2
8. Limiting values	3
9. Thermal characteristics	4
10. Characteristics	5
11. Test information	7
12. Package outline	8
13. Soldering	8
14. Revision history	9
15. Legal information	10

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